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Data Sheet

October 2013

N-Channel Logic Level Power MOSFET 100 V, 12 A, 200 mΩ

These are N-Channel enhancement mode silicon gate power field effect transistors specifically designed for use with logic level (5V) driving sources in applications such as programmable controllers, automotive switching and solenoid drivers. This performance is accomplished through a special gate oxide design which provides full rated conduction at gate biases in the 3V to 5V range, thereby facilitating true on-off power control directly from logic circuit supply voltages.

Formerly developmental type TA09526.

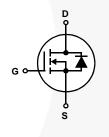
Ordering Information

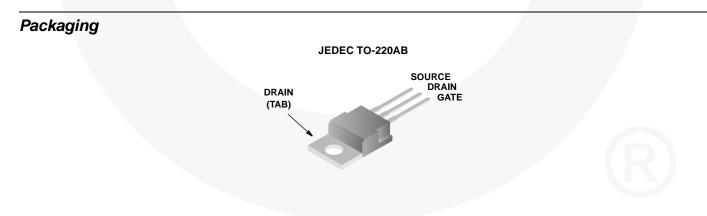
| PART NUMBER | PACKAGE | BRAND |
|-------------|----------|---------|
| RFP12N10L | TO-220AB | F12N10L |

Features

- 12A, 100V
- r_{DS(ON)} = 0.200Ω
- Design Optimized for 5V Gate Drives
- Can be Driven Directly from QMOS, NMOS, TTL Circuits
- Compatible with Automotive Drive Requirements
- SOA is Power-Dissipation Limited
- Nanosecond Switching Speeds
- Linear Transfer Characteristics
- High Input Impedance
- Majority Carrier Device
- Related Literature
 - TB334 "Guidelines for Soldering Surface Mount Components to PC Boards

Symbol





Absolute Maximum Ratings $T_{C} = 25^{\circ}C$, Unless Otherwise Specified

| | RFP12N10L | UNITS |
|--|------------|-------------------|
| Drain to Source Voltage (Note 1)V _{DS} | 100 | V |
| Drain to Gate Voltage (R_{GS} = 1M Ω) (Note 1) | 100 | V |
| Continuous Drain Current I _D | 12 | А |
| Pulsed Drain Current (Note 3) | 30 | А |
| Gate to Source VoltageV _{GS} | ±10 | V |
| Maximum Power Dissipation | 60 | W |
| Above T _C = 25 ^o C, Derate Linearly | 0.48 | W/ ^o C |
| Operating and Storage Temperature | -55 to 150 | °C |
| Maximum Temperature for Soldering Leads at 0.063in (1.6mm) from Case for 10sT _L Package Body for 10s, See Techbrief 334T _{pkg} | 300 260 | °C O° |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. $T_J = 25^{\circ}C$ to $125^{\circ}C$.

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | ТҮР | MAX | UNITS |
|--|---------------------|--|-----|-----|-------|-------|
| Drain to Source Breakdown Voltage | BV _{DSS} | $I_{\rm D} = 250 \mu A, V_{\rm GS} = 0 V$ | 100 | - | - | V |
| Gate to Threshold Voltage | V _{GS(TH)} | $V_{GS} = V_{DS}$, $I_D = 250 \mu A$ (Figure 7) | 1 | - | 2 | V |
| | IDSS | V _{DS} = 80V | - | - | 1 | μΑ |
| Zero Gate Voltage Drain Current | | $V_{GS} = 0V$ $T_C = 125^{\circ}C$ | - | - | 50 | μΑ |
| Gate to Source Leakage Current | I _{GSS} | $V_{GS} = 10V, V_{DS} = 0V$ | - | - | 100 | nA |
| Drain to Source On Resistance (Note 2) | r _{DS(ON)} | $I_D = 12A, V_{GS} = 5V$ (Figures 5, 6) | - | - | 0.200 | Ω |
| Input Capacitance | C _{ISS} | V _{GS} = 0V, V _{DS} = 25V, f = 1MHz (Figure 8) | | - | 900 | pF |
| Output Capacitance | C _{OSS} | | | - | 325 | pF |
| Reverse-Transfer Capacitance | C _{RSS} | | | - | 170 | pF |
| Turn-On Delay Time | t _{d(ON)} | $I_D = 6A, V_{DD} = 50V, R_G = 6.25Ω,$ $V_{GS} = 5V$ (Figures 9, 10, 11) | | 15 | 50 | ns |
| Rise Time | t _r | | | 70 | 150 | ns |
| Turn-Off Delay Time | t _{d(OFF)} | | | 100 | 130 | ns |
| Fall Time | t _f | | - , | 80 | 150 | ns |
| Thermal Resistance Junction to Case | R _{θJC} | TO-220 | / | | 2.083 | oC/W |

Source to Drain Diode Specifications

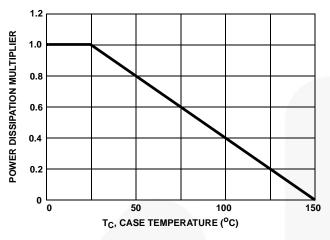
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | ТҮР | MAX | UNITS |
|--|-----------------|---|-----|-----|-----|-------|
| Source to Drain Diode Voltage (Note 2) | V _{SD} | I _{SD} = 6A | - | - | 1.4 | V |
| Diode Reverse Recovery Time | t _{rr} | I _{SD} = 4A, dI _{SD} /dt = 50A/μs | - | 150 | - | ns |

NOTES:

2. Pulsed: pulse duration = 80µs max, duty cycle = 2%.

3. Repetitive rating: pulse width limited by maximum junction temperature.

Typical Performance Curves Unless Otherwise Specified





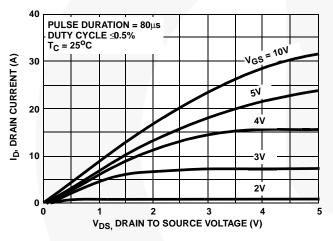
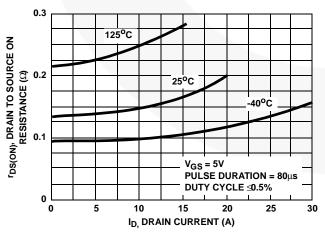


FIGURE 3. SATURATION CHARACTERISTICS





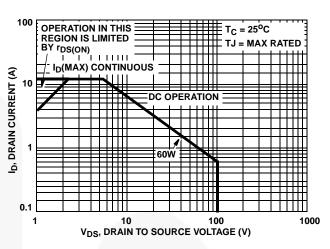
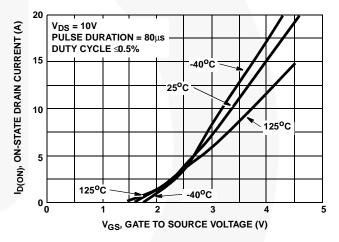


FIGURE 2. FORWARD BIAS OPERATING AREA





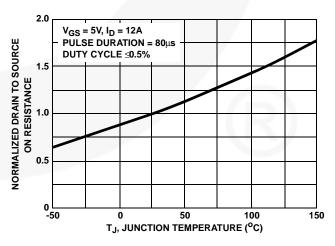
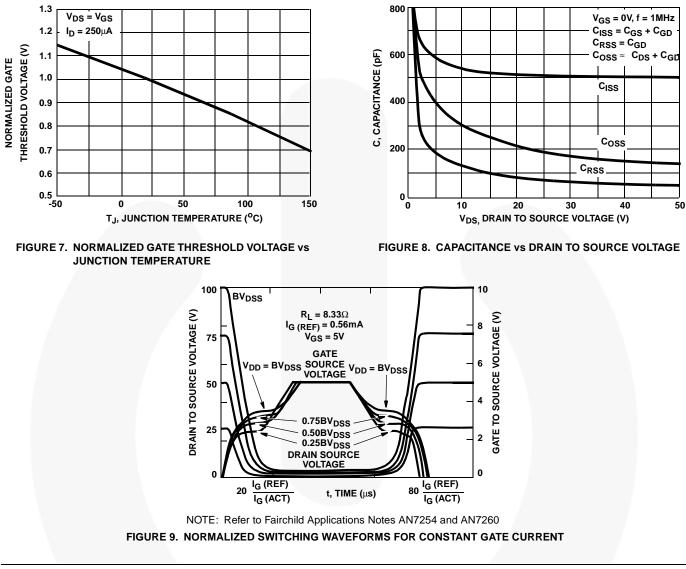


FIGURE 6. NORMALIZED DRAIN TO SOURCE ON RESISTANCE vs JUNCTION TEMPERATURE

Typical Performance Curves Unless Otherwise Specified (Continued)



Test Circuits and Waveforms

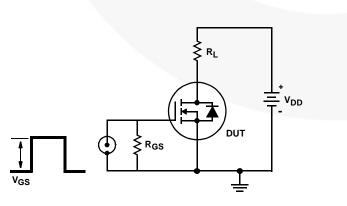


FIGURE 10. SWITCHING TIME TEST CIRCUIT

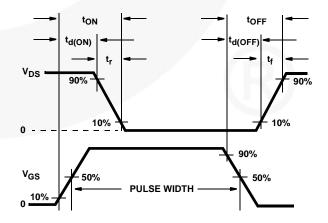


FIGURE 11. RESISTIVE SWITCHING WAVEFORMS

Test Circuits and Waveforms (Continued)

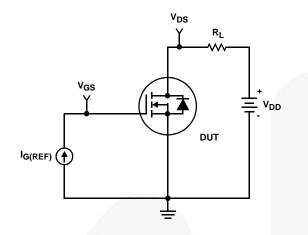
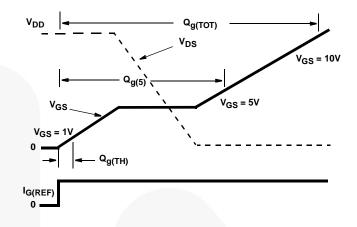


FIGURE 12. GATE CHARGE TEST CIRCUIT





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